

GENERAL DESCRIPTION

The SGM41012 family are battery protection ICs for Li-Ion/polymer rechargeable batteries, including the high-accuracy voltage detection circuits and the delay circuits. The device is designed to protect 1-cell Li-Ion/polymer rechargeable battery pack against over-charge, over-discharge and over-current.

The SGM41012 uses an external over-current detection resistor to achieve high-accuracy over-current protection with less effect from temperature change.

The SGM41012 is available in Green XTDFN-1.4×1.4-6L and UTDFN-1.4×1.8-6L packages. It can operate in the -40°C to +85°C ambient temperature range.

APPLICATIONS

Li-Ion Rechargeable Battery Pack

Lithium Polymer Rechargeable Battery Pack

TYPICAL APPLICATION

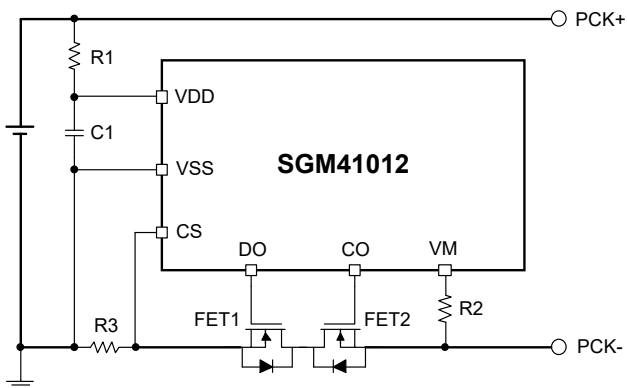


Figure 1. Typical Application Circuit

FEATURES

- **High-Accuracy Voltage Detection Circuit**
 - ♦ **Over-Charge Detection Voltage:** 4.1V to 5.0V (5mV Step), Accuracy: $\pm 15\text{mV}$
 - ♦ **Over-Charge Hysteresis Voltage:** 150mV or 200mV, Accuracy: $\pm 40\text{mV}$
 - ♦ **Over-Discharge Detection Voltage:** 2.35V to 2.8V (50mV Step), Accuracy: $\pm 35\text{mV}$
 - ♦ **Over-Discharge Hysteresis Voltage:** 250mV or 300mV, Accuracy: $\pm 35\text{mV}$
 - ♦ **Discharge Over-Current Detection Voltage 1:** 3mV to 55mV (0.25mV Step), Accuracy: $\pm 0.75\text{mV}$
 - ♦ **Discharge Over-Current Detection Voltage 2:** 6mV to 55mV (0.5mV Step), Accuracy: $\pm 2\text{mV}$
 - ♦ **Load Short-Circuiting Detection Voltage:** 20mV to 100mV (1mV Step), Accuracy: $\pm 4\text{mV}$
 - ♦ **Charge Over-Current Detection Voltage:** -55mV to -3mV (0.25mV Step), Accuracy: $\pm 0.75\text{mV}$
- Detection Delay Times are Generated Only by an Internal Circuit (No External Capacitors Required)
- Discharge Over-Current Control Function
- Low Voltage Battery Charge Permission Voltage: 0V, 0.9V, 1.2V, 1.5V
- Output Available during Power-On
- High-Withstand Voltage
 - ♦ VM and CO Pins: Absolute Maximum Rating -28V
- Operating Temperature Range: -40°C to +85°C
- Low Current Consumption
 - ♦ During Operation: 2.1 μA (TYP) ($T_J = +25^\circ\text{C}$)
 - ♦ After Over-Discharge: 0.35 μA (TYP) ($T_J = +25^\circ\text{C}$)
- Available in Green XTDFN-1.4×1.4-6L and UTDFN-1.4×1.8-6L Packages

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM41012AA	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012AAYUHE6G/TR	1GG XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012AAYXHF6G/TR	1GH XXX	Tape and Reel, 3000
SGM41012AB	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012ABYUHE6G/TR	1V2 XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012ABYXHF6G/TR	1V3 XXX	Tape and Reel, 3000
SGM41012AC	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012ACYUHE6G/TR	1V4 XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012ACYXHF6G/TR	1V5 XXX	Tape and Reel, 3000
SGM41012AD	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012ADYUHE6G/TR	1V6 XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012ADYXHF6G/TR	1V7 XXX	Tape and Reel, 3000
SGM41012AE	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012AEYUHE6G/TR	2QP XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012AEYXHF6G/TR	2R4 XXX	Tape and Reel, 3000
SGM41012AF	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012AFYUHE6G/TR	2QQ XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012AFYXHF6G/TR	2R5 XXX	Tape and Reel, 3000
SGM41012AG	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012AGYUHE6G/TR	2QR XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012AGYXHF6G/TR	2R6 XXX	Tape and Reel, 3000
SGM41012AH	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012AHYUHE6G/TR	2QS XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012AHYXHF6G/TR	2R7 XXX	Tape and Reel, 3000
SGM41012AJ	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012AJYUHE6G/TR	2QT XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012AJYXHF6G/TR	2R8 XXX	Tape and Reel, 3000
SGM41012AK	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012AKYUHE6G/TR	2QU XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012AKYXHF6G/TR	2R9 XXX	Tape and Reel, 3000
SGM41012AL	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012ALYUHE6G/TR	2QV XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012ALYXHF6G/TR	2RA XXX	Tape and Reel, 3000
SGM41012AM	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012AMYUHE6G/TR	2QW XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012AMYXHF6G/TR	2RB XXX	Tape and Reel, 3000
SGM41012AN	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012ANYUHE6G/TR	2QX XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012ANYXHF6G/TR	2RC XXX	Tape and Reel, 3000

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM41012AP	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012APYUHE6G/TR	2QY XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012APYXHF6G/TR	2RD XXX	Tape and Reel, 3000
SGM41012AR	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012ARYUHE6G/TR	2QZ XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012ARYXHF6G/TR	2RE XXX	Tape and Reel, 3000
SGM41012AS	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012ASYUHE6G/TR	2R0 XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012ASYXHF6G/TR	2RF XXX	Tape and Reel, 3000
SGM41012AT	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012ATYUHE6G/TR	2R1 XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012ATYXHF6G/TR	2RG XXX	Tape and Reel, 3000
SGM41012AU	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012AUYUHE6G/TR	2R2 XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012AUYXHF6G/TR	2RH XXX	Tape and Reel, 3000
SGM41012AX	UTDFN-1.4×1.8-6L	-40°C to +85°C	SGM41012AXYUHE6G/TR	2R3 XXX	Tape and Reel, 3000
	XTDFN-1.4×1.4-6L	-40°C to +85°C	SGM41012AXYXHF6G/TR	2RI XXX	Tape and Reel, 3000

MARKING INFORMATION

NOTE: XXX = Date Code and Trace Code.

Y Y Y — Serial Number

X X X

└──┬──┘ Trace Code

└──┬──┘ Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

PRODUCT LIST

Table 1. Product Name List

Product Name ⁽¹⁾	Over-Charge Detection Voltage (V _{CU})	Over-Charge Release Voltage (V _{CL})	Over-Discharge Detection Voltage (V _{DL})	Over-Discharge Release Voltage (V _{DU})	Discharge Over-Current Detection Voltage 1 (V _{DIOV1})	Discharge Over-Current Detection Voltage 2 (V _{DIOV2})	Load Short-Circuiting Detection Voltage (V _{SHORT})	Charge Over-Current Detection Voltage (V _{CIOV})	0V Battery Charge Inhibition Threshold (V _{OINH})	Delay Time Combination ⁽²⁾
SGM41012AA	4.605V	4.455V	2.450V	2.700V	8mV	12mV	20mV	-13mV	0V	(9)
SGM41012AB	4.655V	4.455V	2.350V	2.650V	8mV	12mV	20mV	-13mV	0V	(9)
SGM41012AC	4.500V	4.300V	2.500V	2.800V	5.6mV	8.5mV	22.5mV	-11.3mV	0V	(1)
SGM41012AD	4.545V	4.345V	2.500V	2.800V	5.6mV	8.5mV	22.5mV	-11.3mV	0V	(1)
SGM41012AE	4.595V	4.395V	2.500V	2.800V	10.5mV	15mV	22.5mV	-18mV	0V	(4)
SGM41012AF	4.615V	4.415V	2.350V	2.650V	10.5mV	15mV	22.5mV	-18mV	0V	(5)
SGM41012AG	4.475V	4.275V	2.500V	2.800V	15mV	19mV	40mV	-11.3mV	0V	(9)
SGM41012AH	4.495V	4.295V	2.350V	2.650V	15mV	19mV	40mV	-11.3mV	0V	(5)
SGM41012AJ	4.495V	4.295V	2.500V	2.800V	14mV	18mV	40mV	-15mV	0V	(9)
SGM41012AK	4.580V	4.380V	2.600V	2.900V	7mV	11mV	22mV	-15mV	0V	(6)
SGM41012AL	4.600V	4.400V	2.350V	2.600V	7mV	11mV	22mV	-18mV	0V	(7)
SGM41012AM	4.590V	4.390V	2.500V	2.800V	10.5mV	15mV	22.5mV	-18mV	0V	(8)
SGM41012AN	4.610V	4.410V	2.350V	2.600V	10.5mV	15mV	26.25mV	-18mV	0V	(9)
SGM41012AP	4.475V	4.325V	2.500V	2.800V	16mV	20mV	40mV	-16mV	0V	(2)
SGM41012AR	4.475V	4.275V	2.500V	2.800V	16mV	20mV	40mV	-16mV	0V	(9)
SGM41012AS	4.520V	4.370V	2.350V	2.600V	7mV	14mV	28mV	-14mV	0V	(1)
SGM41012AT	4.555V	4.405V	2.600V	2.850V	7mV	11mV	22mV	-13mV	0V	(3)
SGM41012AU	4.595V	4.445V	2.350V	2.650V	11.5mV	15mV	22.5mV	-18mV	0V	(7)
SGM41012AX	4.555V	4.355V	2.600V	2.900V	7mV	11mV	22mV	-13mV	0V	(3)

NOTES:

1. The product name is in range of SGM41012AA to SGM41012ZZ. For products other than the above, please contact our sales representatives.
2. Please refer to the Table 2 for details of the delay time combinations.

PRODUCT LIST (continued)

Table 2. Delay Time Combination

Delay Time Combination ⁽³⁾	Over-Charge Detection Delay Time (t_{CU})	Over-Discharge Detection Delay Time (t_{DL})	Discharge Over-Current Detection Delay Time 1 (t_{DIOV1})	Discharge Over-Current Detection Delay Time 2 (t_{DIOV2})	Load Short-Circuiting Detection Delay Time (t_{SHORT})	Charge Over-Current Detection Delay Time (t_{CIOV})
(1)	512ms	60ms	2048ms	20ms	280μs	36ms
(2)	1024ms	60ms	4096ms	20ms	280μs	68ms
(3)	1024ms	60ms	4096ms	20ms	280μs	20ms
(4)	1024ms	60ms	2048ms	20ms	280μs	20ms
(5)	1024ms	128ms	1024ms	20ms	280μs	20ms
(6)	1024ms	60ms	4096ms	20ms	280μs	20ms
(7)	512ms	128ms	4096ms	20ms	280μs	36ms
(8)	512ms	60ms	4096ms	36ms	280μs	36ms
(9)	1024ms	60ms	4096ms	20ms	280μs	36ms

NOTE:

3. The delay times can be changed within the range shown in Table 3. Please contact our sales representatives for more information.

Table 3. Delay Time Options

Delay Time	Symbol	Selection Range				Remark
Over-Charge Detection Delay Time	t_{CU}	512ms	1024ms			Select a value from the left.
Over-Discharge Detection Delay Time	t_{DL}	60ms	128ms			Select a value from the left.
Discharge Over-Current Detection Delay Time 1	t_{DIOV1}	512ms	1024ms	2048ms	4096ms	Select a value from the left.
Discharge Over-Current Detection Delay Time 2	t_{DIOV2}	20ms	36ms			Select a value from the left.
Load Short-Circuiting Detection Delay Time	t_{SHORT}	280μs	560μs			Select a value from the left.
Charge Over-Current Detection Delay Time	t_{CIOV}	20ms	36ms	68ms		Select a value from the left.

ABSOLUTE MAXIMUM RATINGS

Input Voltage Range between VDD Pin and VSS Pin, V_{DS}	$V_{SS} - 0.3V$ to $V_{SS} + 12V$
CS Pin Input Voltage Range, V_{CS}	$V_{SS} - 0.3V$ to $V_{SS} + 5V$
VM Pin Input Voltage Range, V_{VM}	$V_{DD} - 28V$ to $V_{DD} + 0.3V$
DO Pin Output Voltage Range, V_{DO}	$V_{SS} - 0.3V$ to $V_{DD} + 0.3V$
CO Pin Output Voltage Range, V_{CO}	$V_{DD} - 28V$ to $V_{DD} + 0.3V$
Package Thermal Resistance	
UTDFN-1.4×1.8-6L, θ_{JA}	135.5°C/W
UTDFN-1.4×1.8-6L, θ_{JB}	92.8°C/W
UTDFN-1.4×1.8-6L, $\theta_{JC (TOP)}$	103.4°C/W
UTDFN-1.4×1.8-6L, $\theta_{JC (BOT)}$	67.7°C/W
XTDFN-1.4×1.4-6L, θ_{JA}	138.2°C/W
XTDFN-1.4×1.4-6L, θ_{JB}	74.6°C/W
XTDFN-1.4×1.4-6L, $\theta_{JC (TOP)}$	84.7°C/W
XTDFN-1.4×1.4-6L, $\theta_{JC (BOT)}$	77.7°C/W
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility ^{(1) (2)}	
HBM	±5000V
CDM	±1000V

NOTES:

1. For human body model (HBM), all pins comply with ANSI/ESDA/JEDEC JS-001 specifications.
2. For charged device model (CDM), all pins comply with ANSI/ESDA/JEDEC JS-002 specifications.

RECOMMENDED OPERATING CONDITIONS

Supply Voltage Range	0V to 6V
Operating Temperature Range	-40°C to +85°C

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

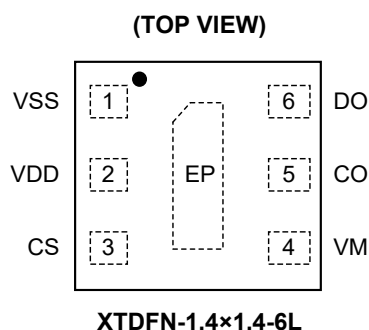
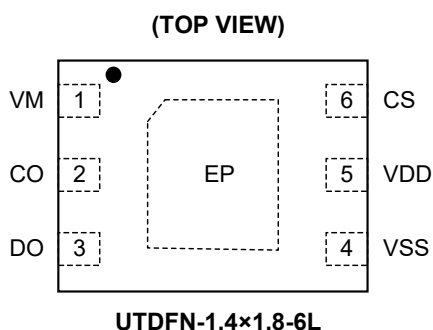
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATIONS



PIN DESCRIPTION

PIN		NAME	TYPE	FUNCTION
UTDNF-1.4×1.8-6L	XTDFN-1.4×1.4-6L			
1	4	VM	I	External Negative Voltage Input Pin.
2	5	CO	O	Charge Control FET Gate Connection Pin (CMOS Output).
3	6	DO	O	Discharge Control FET Gate Connection Pin (CMOS Output).
4	1	VSS	I	Negative Power Supply Input Pin.
5	2	VDD	I	Positive Power Supply Input Pin.
6	3	CS	I	Over-Current Detection Input Pin.
Exposed Pad	Exposed Pad	EP	–	Exposed Pad. It is recommended to leave this pin floating.

NOTE: I = input, O = output.

ELECTRICAL CHARACTERISTICS

(T_J = -40°C to +85°C, typical values are measured at T_J = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Detection Voltage							
Over-Charge Detection Voltage ⁽¹⁾	V _{CU}	Test circuit 1, see Figure 3	T _J = +25°C	V _{CU} - 0.015	V _{CU}	V _{CU} + 0.015	V
			T _J = -25°C to +70°C	V _{CU} - 0.028		V _{CU} + 0.020	
			T _J = -40°C to +85°C	V _{CU} - 0.040		V _{CU} + 0.025	
Over-Charge Release Voltage ⁽¹⁾	V _{CL}	V _{CL} ≠ V _{CU} , test circuit 1, see Figure 3	T _J = +25°C	V _{CL} - 0.040	V _{CL}	V _{CL} + 0.040	V
			T _J = -25°C to +70°C	V _{CL} - 0.050		V _{CL} + 0.050	
			T _J = -40°C to +85°C	V _{CL} - 0.055		V _{CL} + 0.055	
Over-Charge Hysteresis Voltage	V _{OCHYS}	150mV option			150		mV
		200mV option			200		
Over-Discharge Detection Voltage ⁽¹⁾	V _{DL}	Test circuit 2, see Figure 4	T _J = +25°C	V _{DL} - 0.035	V _{DL}	V _{DL} + 0.035	V
			T _J = -25°C to +70°C	V _{DL} - 0.040		V _{DL} + 0.040	
			T _J = -40°C to +85°C	V _{DL} - 0.045		V _{DL} + 0.045	
Over-Discharge Release Voltage ⁽¹⁾	V _{DU}	Test circuit 2, see Figure 4	T _J = +25°C	V _{DU} - 0.035	V _{DU}	V _{DU} + 0.035	V
			T _J = -25°C to +70°C	V _{DU} - 0.050		V _{DU} + 0.050	
			T _J = -40°C to +85°C	V _{DU} - 0.060		V _{DU} + 0.060	
Over-Discharge Hysteresis Voltage	V _{ODHYS}	250mV option			250		mV
		300mV option			300		
Discharge Over-Current Detection Voltage 1 ⁽¹⁾	V _{DIOV1}	Test circuit 5, see Figure 7	T _J = +25°C	V _{DIOV1} - 0.75	V _{DIOV1}	V _{DIOV1} + 0.75	mV
			T _J = -25°C to +70°C	V _{DIOV1} - 1.25		V _{DIOV1} + 1.25	
			T _J = -40°C to +85°C	V _{DIOV1} - 1.25		V _{DIOV1} + 1.25	
Discharge Over-Current Detection Voltage 2 ⁽¹⁾	V _{DIOV2}	Test circuit 2, see Figure 4	T _J = +25°C	V _{DIOV2} - 2.0	V _{DIOV2}	V _{DIOV2} + 2.0	mV
			T _J = -25°C to +70°C	V _{DIOV2} - 2.2		V _{DIOV2} + 2.2	
			T _J = -40°C to +85°C	V _{DIOV2} - 2.2		V _{DIOV2} + 2.2	
Load Short-Circuiting Detection Voltage	V _{SHORT}	Test circuit 2, see Figure 4		V _{SHORT} - 4	V _{SHORT}	V _{SHORT} + 4	mV
Load Short-Circuiting Detection Voltage 2	V _{SHORT2}	Test circuit 2, see Figure 4		V _{DD} - 1.2	V _{DD} - 0.65	V _{DD} - 0.5	V
Charge Over-Current Detection Voltage ⁽¹⁾	V _{CIOV}	Test circuit 2, see Figure 4	T _J = +25°C	V _{CIOV} - 0.75	V _{CIOV}	V _{CIOV} + 0.75	mV
			T _J = -25°C to +70°C	V _{CIOV} - 1.25		V _{CIOV} + 1.25	
			T _J = -40°C to +85°C	V _{CIOV} - 1.25		V _{CIOV} + 1.25	
Load Short-Circuiting 2 Release Voltage	V _{RIOV}	V _{DD} = 3.4V, test circuit 2, see Figure 4		V _{DD} - 2	V _{DD} - 1.5	V _{DD} - 1	V
0V Battery Charge							
0V Battery Charge Starting Charger Voltage	V _{0CHA}	0V battery charge enabled, test circuit 4, see Figure 6	T _J = +25°C	1	1.33	1.65	V
			T _J = -25°C to +70°C	0.7	1.33	1.75	
			T _J = -40°C to +85°C	0.6	1.33	1.9	
Internal Resistance							
Resistance between VDD Pin and VM Pin	R _{VMD}	V _{DD} = 1.8V, V _{VM} = 1V, test circuit 3, see Figure 5	T _J = +25°C	800	1150	1500	kΩ
			T _J = -25°C to +70°C	700	1150	1650	
			T _J = -40°C to +85°C	650	1150	1650	
Resistance between VM Pin and VSS Pin	R _{VMS}	V _{DD} = 3.4V, V _{VM} = 1.0V, test circuit 3, see Figure 5	T _J = +25°C	8	12.5	17	kΩ
			T _J = -25°C to +70°C	7.5	12.5	18	
			T _J = -40°C to +85°C	6.5	12.5	20	

ELECTRICAL CHARACTERISTICS (continued)(T_J = -40°C to +85°C, typical values are measured at T_J = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Input Voltage							
Operation Voltage between VDD Pin and VSS Pin	V _{DSOP1}			0		12	V
Operation Voltage between VDD Pin and VM Pin	V _{DSOP2}			1.5		28	V
Input Current							
Current Consumption during Operation	I _{OPE}	V _{DD} = 3.4V, V _{VM} = 0V, test circuit 3, see Figure 5	T _J = +25°C		2.1	2.6	μA
			T _J = -25°C to +70°C		2.1	4.0	
			T _J = -40°C to +85°C		2.1	5.0	
Current Consumption during Over-Discharge	I _{OPED}	V _{DD} = V _{VM} = 1.9V, test circuit 3, see Figure 5	T _J = +25°C		0.35	0.5	μA
			T _J = -25°C to +70°C		0.35	0.7	
			T _J = -40°C to +85°C		0.35	1	
Output Resistance							
CO Pin Resistance "H"	R _{COH}	Test circuit 4, see Figure 6	T _J = +25°C	5.0	7.3	10.0	kΩ
			T _J = -25°C to +70°C	4.5	7.3	11.0	
			T _J = -40°C to +85°C	4.0	7.3	12.0	
CO Pin Resistance "L"	R _{COL}	Test circuit 4, see Figure 6	T _J = +25°C	2.5	3.6	4.5	kΩ
			T _J = -25°C to +70°C	2.0	3.6	4.8	
			T _J = -40°C to +85°C	1.8	3.6	5.0	
DO Pin Resistance "H"	R _{DOH}	Test circuit 4, see Figure 6	T _J = +25°C	5.5	7.7	10.5	kΩ
			T _J = -25°C to +70°C	5.0	7.7	11.5	
			T _J = -40°C to +85°C	4.5	7.7	12.5	
DO Pin Resistance "L"	R _{DOL}	Test circuit 4, see Figure 6	T _J = +25°C	2.0	3.4	5.4	kΩ
			T _J = -25°C to +70°C	1.4	3.4	6.5	
			T _J = -40°C to +85°C	1.0	3.4	7.0	
Delay Time ⁽¹⁾							
Over-Charge Detection Delay Time	t _{CU}	Test circuit 5, see Figure 7	T _J = +25°C	t _{CU} × 0.75	t _{CU}	t _{CU} × 1.43	ms
			T _J = -25°C to +70°C	t _{CU} × 0.61		t _{CU} × 1.55	
			T _J = -40°C to +85°C	t _{CU} × 0.53		t _{CU} × 1.63	
Over-Discharge Detection Delay Time	t _{DL}	Test circuit 5, see Figure 7	T _J = +25°C	t _{DL} × 0.60	t _{DL}	t _{DL} × 1.44	ms
			T _J = -25°C to +70°C	t _{DL} × 0.49		t _{DL} × 1.56	
			T _J = -40°C to +85°C	t _{DL} × 0.42		t _{DL} × 1.64	
Discharge Over-Current Detection Delay Time 1	t _{DIOV1}	Test circuit 5, see Figure 7	T _J = +25°C	t _{DIOV1} × 0.75	t _{DIOV1}	t _{DIOV1} × 1.65	ms
			T _J = -25°C to +70°C	t _{DIOV1} × 0.61		t _{DIOV1} × 1.79	
			T _J = -40°C to +85°C	t _{DIOV1} × 0.53		t _{DIOV1} × 1.88	
Discharge Over-Current Detection Delay Time 2	t _{DIOV2}	Test circuit 5, see Figure 7	T _J = +25°C	t _{DIOV2} × 0.60	t _{DIOV2}	t _{DIOV2} × 1.33	ms
			T _J = -25°C to +70°C	t _{DIOV2} × 0.49		t _{DIOV2} × 1.43	
			T _J = -40°C to +85°C	t _{DIOV2} × 0.42		t _{DIOV2} × 1.51	

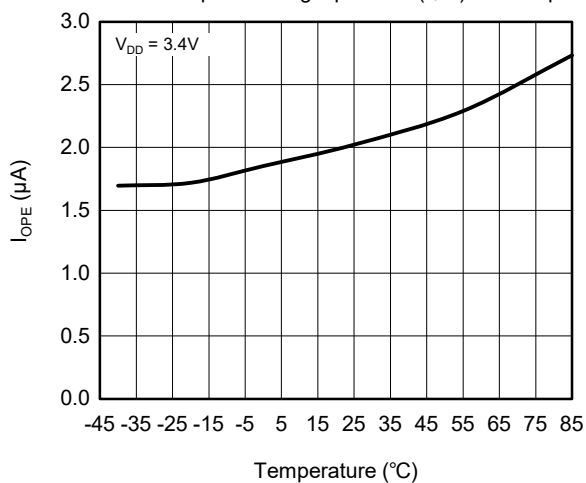
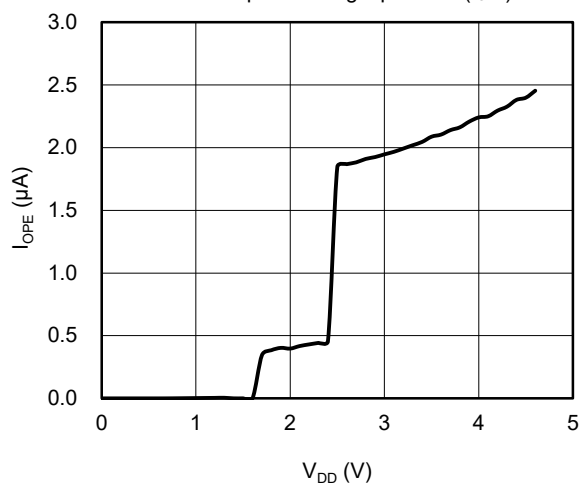
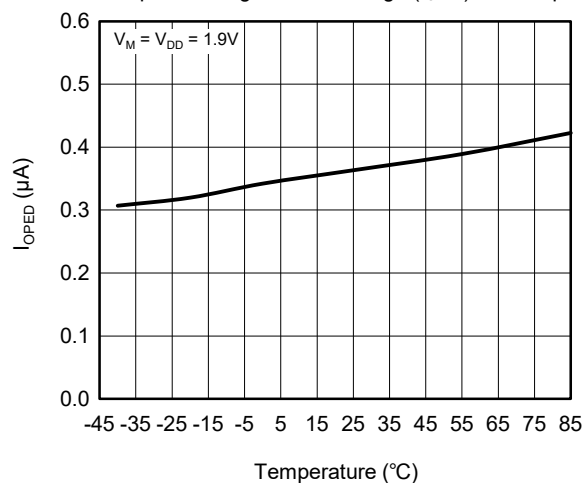
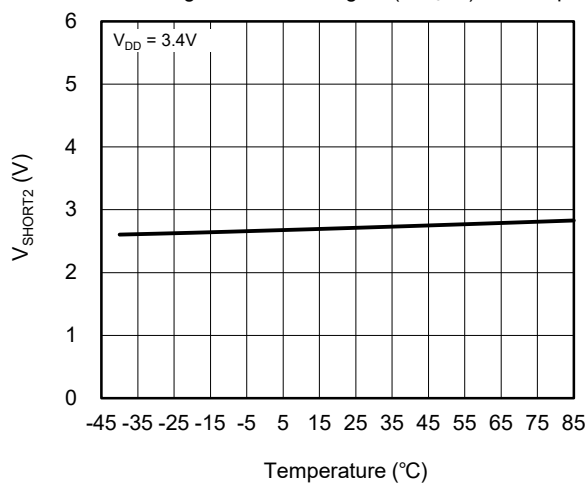
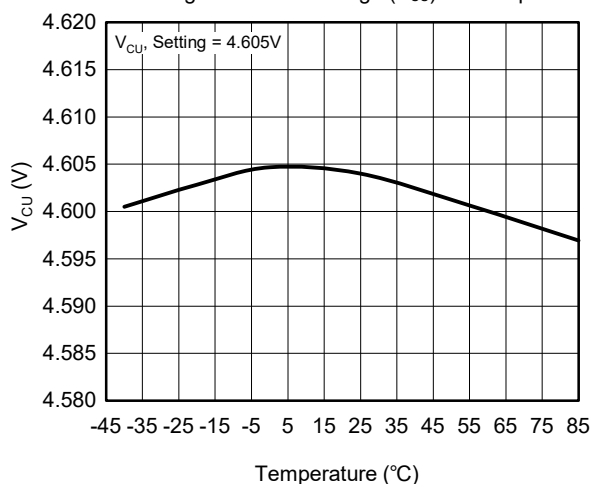
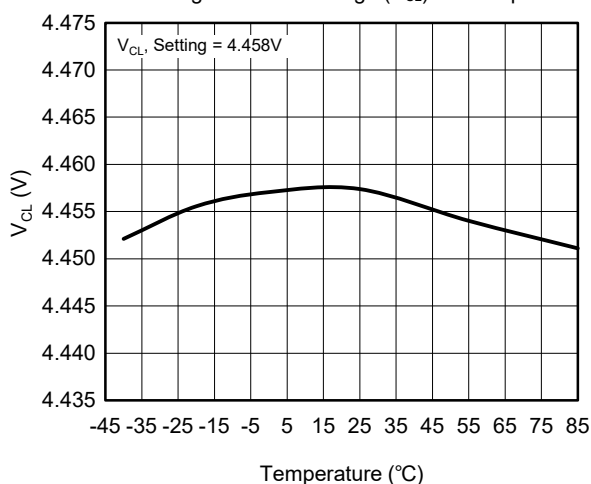
ELECTRICAL CHARACTERISTICS (continued)(T_J = -40°C to +85°C, typical values are measured at T_J = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Delay Time							
Load Short-Circuiting Detection Delay Time	t _{SHORT}	Test circuit 5, see Figure 7	T _J = +25°C	t _{SHORT} × 0.75	t _{SHORT}	t _{SHORT} × 1.20	μs
			T _J = -25°C to +70°C	t _{SHORT} × 0.61		t _{SHORT} × 1.30	
			T _J = -40°C to +85°C	t _{SHORT} × 0.53		t _{SHORT} × 1.37	
Charge Over-Current Detection Delay Time	t _{CIOV}	Test circuit 5, see Figure 7	T _J = +25°C	t _{CIOV} × 0.60	t _{CIOV}	t _{CIOV} × 1.33	ms
			T _J = -25°C to +70°C	t _{CIOV} × 0.49		t _{CIOV} × 1.43	
			T _J = -40°C to +85°C	t _{CIOV} × 0.42		t _{CIOV} × 1.51	

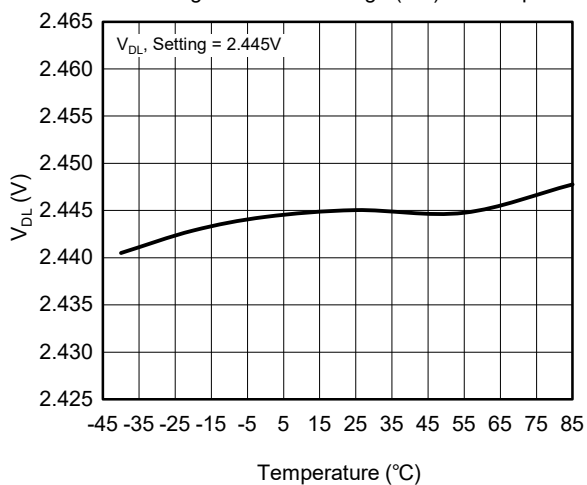
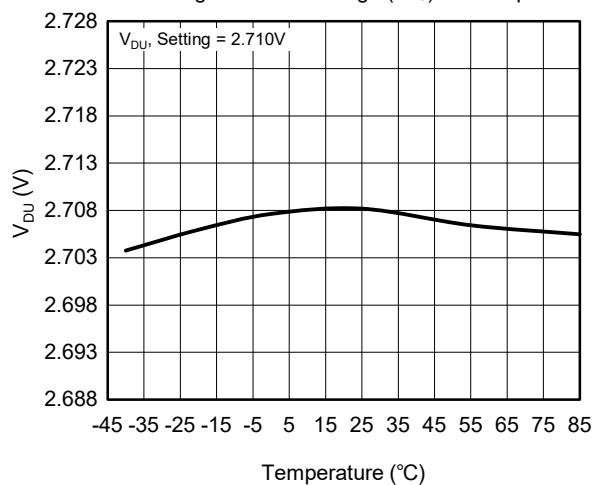
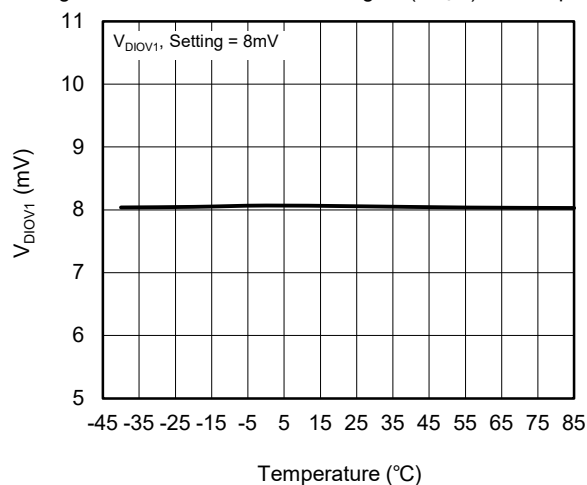
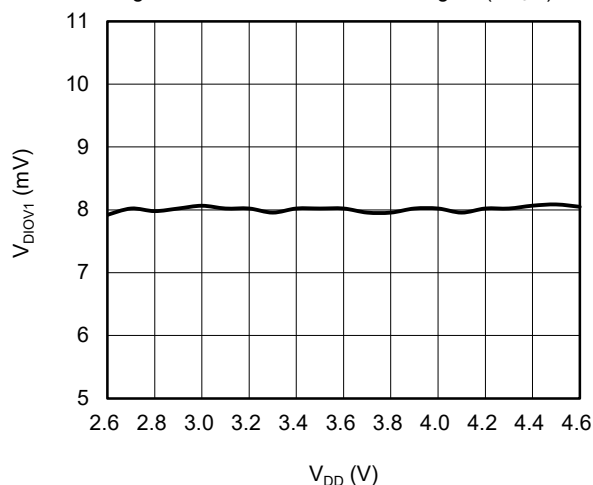
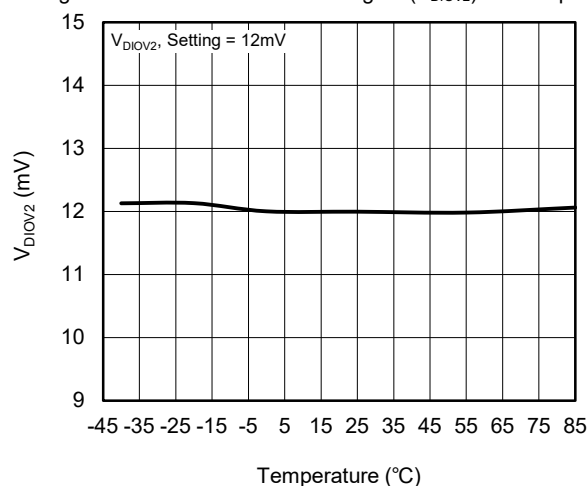
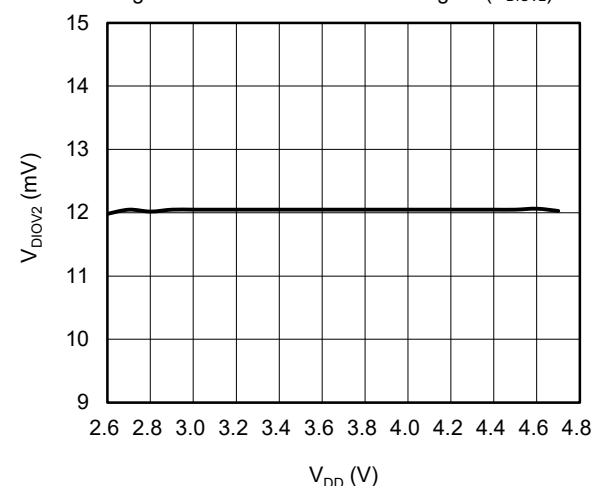
NOTE:

1. The best estimate from product characterization, guaranteed by correlated test in production.

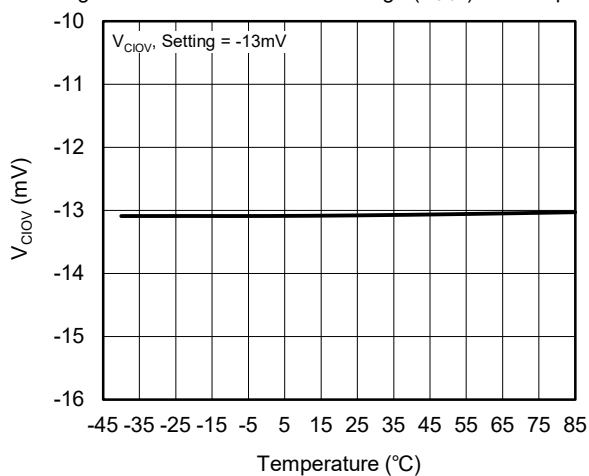
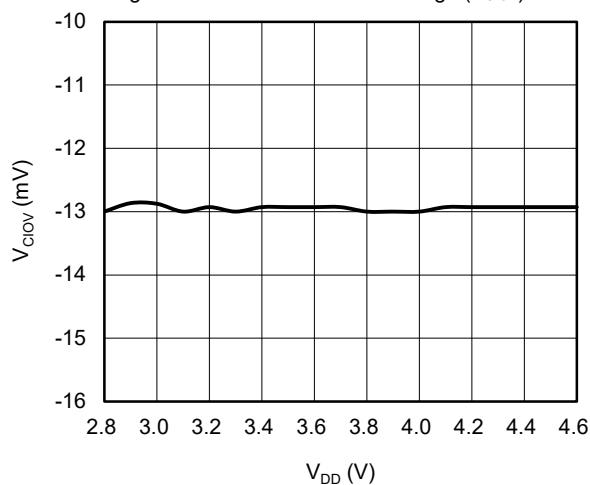
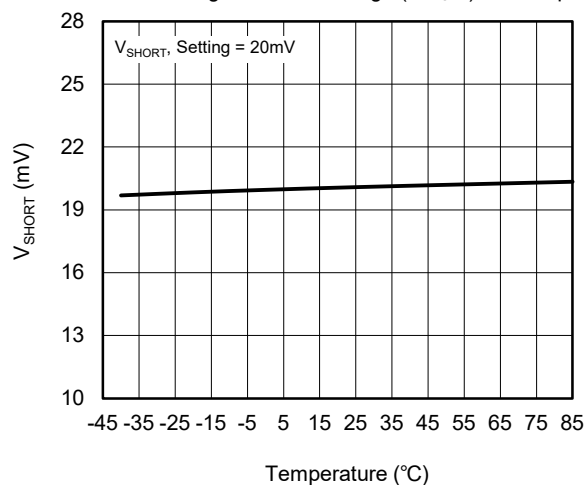
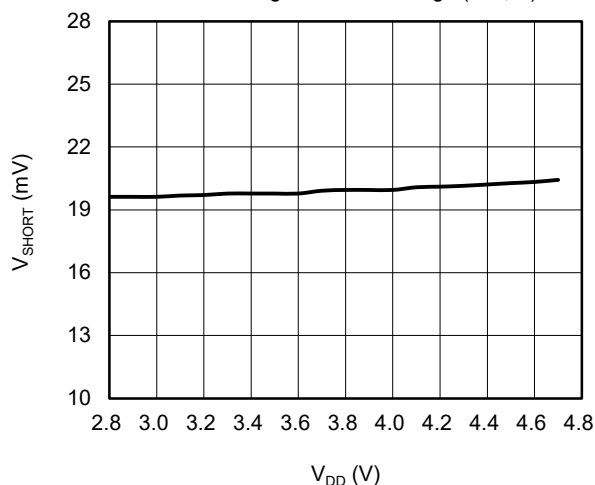
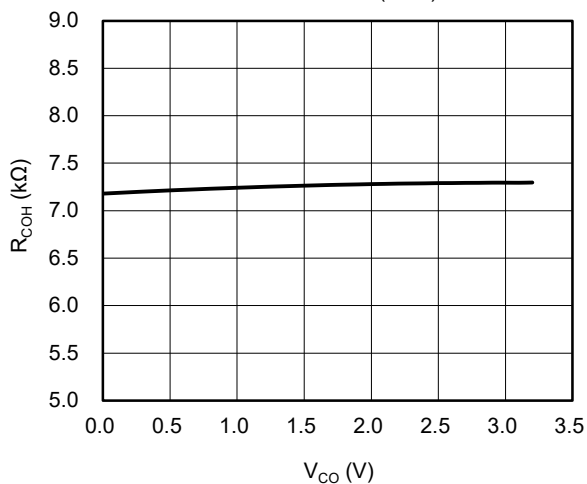
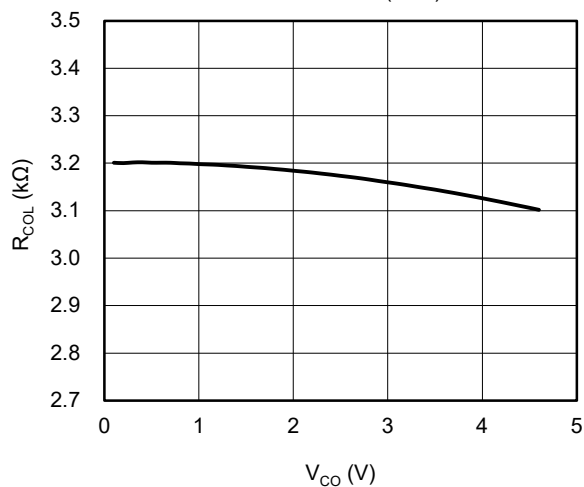
TYPICAL PERFORMANCE CHARACTERISTICS

Current Consumption during Operation (I_{OPE}) vs. TemperatureCurrent Consumption during Operation (I_{OPE}) vs. V_{DD} Current Consumption during Over-Discharge (I_{OPED}) vs. TemperatureLoad Short-Circuiting Detection Voltage 2 (V_{SHORT2}) vs. TemperatureOver-Charge Detection Voltage (V_{CU}) vs. TemperatureOver-Charge Release Voltage (V_{CL}) vs. Temperature

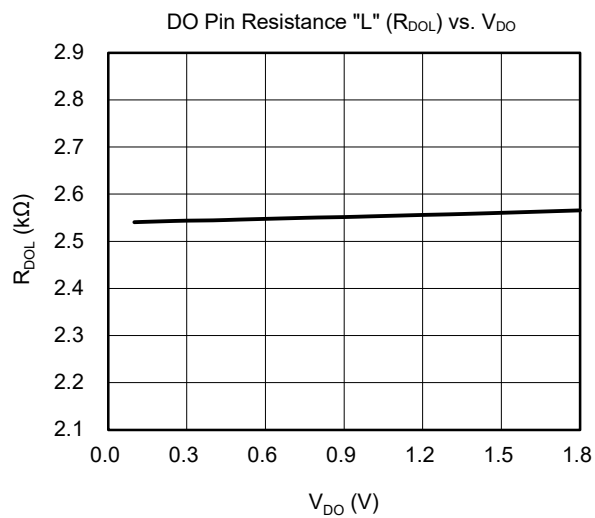
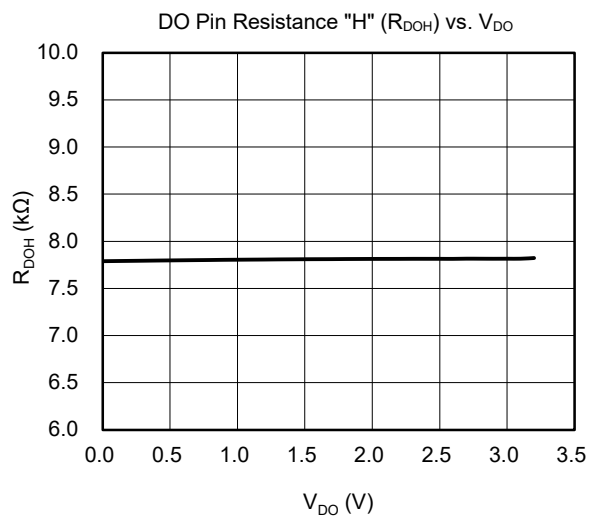
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Over-Discharge Detection Voltage (V_{DL}) vs. TemperatureOver-Discharge Release Voltage (V_{DU}) vs. TemperatureDischarge Over-Current Detection Voltage 1 (V_{DIOV1}) vs. TemperatureDischarge Over-Current Detection Voltage 1 (V_{DIOV1}) vs. V_{DD} Discharge Over-Current Detection Voltage 2 (V_{DIOV2}) vs. TemperatureDischarge Over-Current Detection Voltage 2 (V_{DIOV2}) vs. V_{DD} 

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Charge Over-Current Detection Voltage (V_{CIOV}) vs. TemperatureCharge Over-Current Detection Voltage (V_{CIOV}) vs. V_{DD} Load Short-Circuiting Detection Voltage (V_{SHORT}) vs. TemperatureLoad Short-Circuiting Detection Voltage (V_{SHORT}) vs. V_{DD} CO Pin Resistance "H" (R_{COH}) vs. V_{CO} CO Pin Resistance "L" (R_{COL}) vs. V_{CO} 

TYPICAL PERFORMANCE CHARACTERISTICS (continued)



FUNCTIONAL BLOCK DIAGRAM

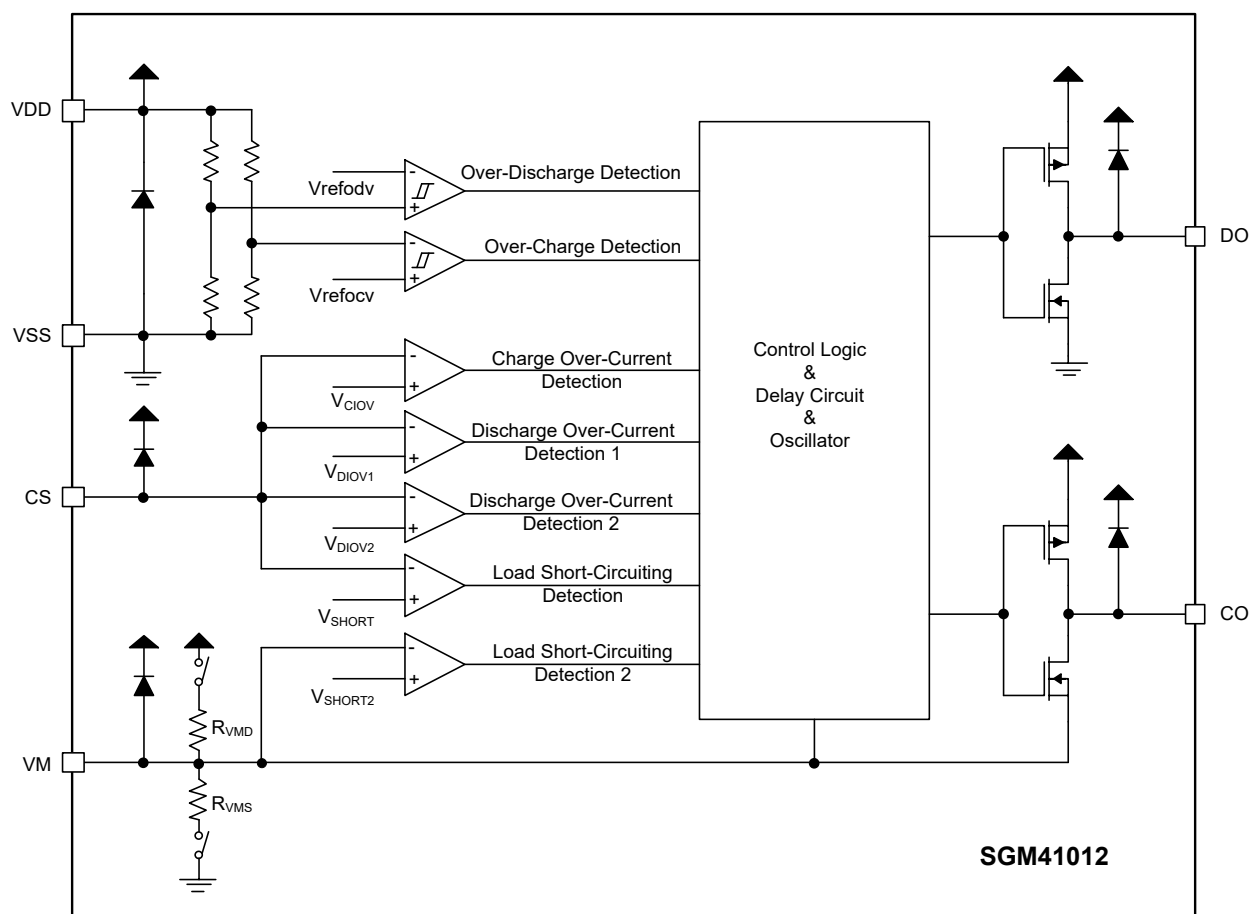


Figure 2. Block Diagram

TEST CIRCUITS

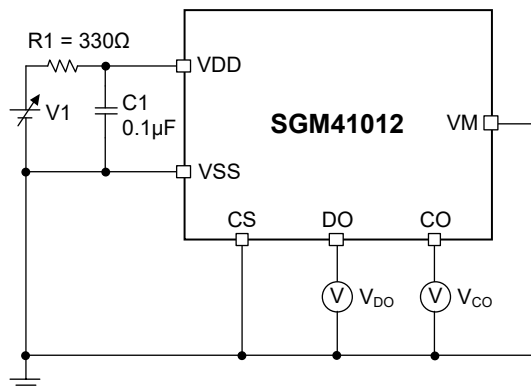


Figure 3. Test Circuit 1

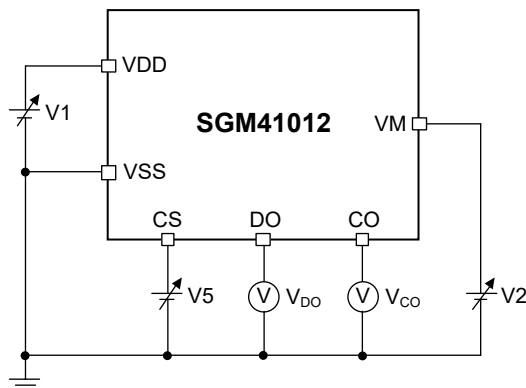


Figure 4. Test Circuit 2

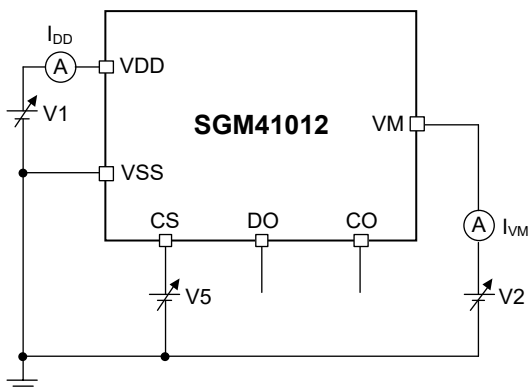


Figure 5. Test Circuit 3

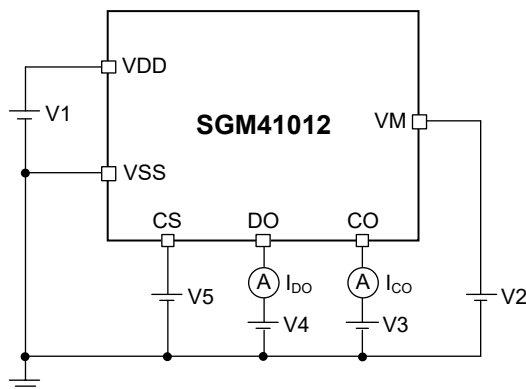


Figure 6. Test Circuit 4

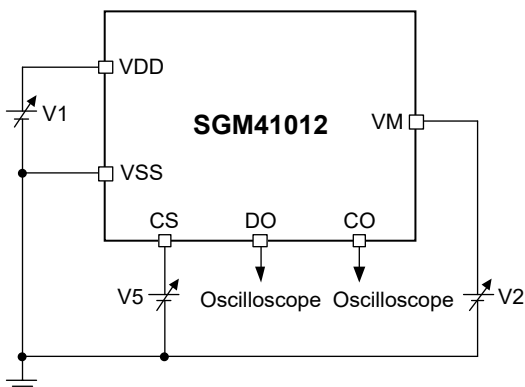


Figure 7. Test Circuit 5

TEST CIRCUITS (continued)

Note that unless otherwise specified, the CO pin output logic level respects to V_{VM} and the DO pin level respects to V_{SS} . And the output voltage levels "H" and "L" at both CO and DO pins are judged by the threshold voltage (typical 1.0V) of the N-FET.

Over-Charge Detection Voltage & Release Voltage (Test Circuit 1)

V_{CU} : Over-charge detection voltage, it is defined as the V1 voltage at which V_{CO} goes from "H" to "L" when gradually increasing V1 voltage after setting $V1 = 3.4V$.

V_{CL} : Over-charge release voltage, it is defined as the V1 voltage at which V_{CO} goes from "L" to "H" when gradually decreasing the V1 voltage.

V_{OCHYS} : Over-charge hysteresis voltage, it is defined as $V_{CU} - V_{CL}$.

Over-Discharge Detection Voltage & Release Voltage (Test Circuit 2)

V_{DL} : Over-discharge detection voltage, it is defined as the V1 voltage at which V_{DO} goes from "H" to "L" when gradually decreasing V1 voltage after setting $V1 = 3.4V$, $V2 = V5 = 0V$.

V_{DU} : Over-discharge release voltage, it is defined as the V1 voltage at which V_{DO} goes from "L" to "H" when setting $V2 = 0.01V$, $V5 = 0V$ and gradually increasing the V1 voltage.

V_{ODHYS} : Over-discharge hysteresis voltage, it is defined as $V_{DU} - V_{DL}$.

Discharge Over-Current Detection Voltage 1 (Test Circuit 5)

V_{DIOV1} : Discharge over-current detection voltage 1, it is defined as the V5 voltage at which V_{DO} goes from "H" to "L" with a delay time t_{DIOV1} when increasing the V5 voltage after setting $V1 = 3.4V$, $V2 = 1.4V$, $V5 = 0V$.

Discharge Over-Current Detection Voltage 2 (Test Circuit 5)

V_{DIOV2} : Discharge over-current detection voltage 2, it is defined as the V5 voltage at which V_{DO} goes from "H" to "L" with a delay time t_{DIOV2} when increasing the V5 voltage after setting $V1 = 3.4V$, $V2 = 1.4V$, $V5 = 0V$.

Load Short-Circuiting Detection Voltage (Test Circuit 2)

V_{SHORT} : Load short-circuiting detection voltage, it is defined as the V5 voltage at which V_{DO} changing from "H" to "L" with a delay time t_{SHORT} when the V5 voltage increasing after setting $V1 = 3.4V$, $V2 = 1.4V$, $V5 = 0V$.

Load Short-Circuiting Detection Voltage 2 & Release Voltage (Test Circuit 2)

V_{SHORT2} : Load short-circuiting detection voltage 2, it is defined as the V2 voltage at which V_{DO} changing from "H" to "L" with a

delay time t_{SHORT} when the V2 voltage increasing after setting $V1 = 3.4V$, $V2 = V5 = 0V$.

V_{RIOV} : Discharge over-current release voltage, it is defined as the V2 voltage at which V_{DO} goes from "L" to "H" when setting $V2 = 3.4V$, $V5 = 0V$ and then gradually decreasing the V2 voltage.

V_{DO} changes to "H" after the V2 voltage falls lower than V_{RIOV} for 1ms (typical), and it maintains "H" during load short-circuiting detection delay time (t_{SHORT}).

Charge Over-Current Detection Voltage (Test Circuit 2)

V_{CIOV} : Charge over-current detection voltage, it is defined as the V5 voltage at which V_{CO} changing from "H" to "L" with a charge over-current detection delay time (t_{CIOV}) when the V5 voltage decreasing after setting $V1 = 3.4V$, $V2 = V5 = 0V$.

Current Consumption (Test Circuit 3)

I_{OPE} : Current consumption during operation, it is defined as the current that flows through the VDD pin (I_{DD}) under conditions of $V1 = 3.4V$, $V2 = V5 = 0V$ during operation.

I_{OPED} : Current consumption during over-discharge, it is defined as I_{DD} under conditions of $V1 = V2 = 1.5V$, $V5 = 0V$ during over-discharge.

Resistance between VDD Pin and VM Pin (Test Circuit 3)

R_{VMD} : Resistance between VDD pin and VM pin, it is tested under conditions of $V1 = 1.8V$, $V2 = 1V$, $V5 = 0V$.

Resistance between VM Pin and VSS Pin (Test Circuit 3)

R_{VMS} : Resistance between VM pin and VSS pin, it is tested under conditions of $V1 = 3.4V$, $V2 = 3V$, $V5 = 0V$.

CO & DO Pin Resistance "H" & "L" (Test Circuit 4)

R_{COH} : CO pin resistance "H", it is defined as the resistance between the VDD pin and CO pin under conditions of $V1 = 3.4V$, $V2 = V5 = 0V$, $V3 = 3.0V$.

R_{COL} : CO pin resistance "L", it is defined as the resistance between the VM pin and CO pin under conditions of $V1 = 4.7V$, $V2 = V5 = 0V$, $V3 = 0.4V$.

R_{DOH} : DO pin resistance "H", it is defined as the resistance between the VDD pin and DO pin under conditions of $V1 = 3.4V$, $V2 = V5 = 0V$, $V4 = 3.0V$.

R_{DOL} : DO pin resistance "L", it is defined as the resistance between the VSS pin and DO pin under conditions of $V1 = 1.8V$, $V2 = V5 = 0V$, $V4 = 0.4V$.

TEST CIRCUITS (continued)

Over-Charge & Over-Discharge Detection Delay Time (Test Circuit 5)

t_{CU} : Over-charge detection delay time, it is defined as the interval time from V1 voltage exceeds V_{CU} until V_{CO} goes to "L", after setting V1 = 3.4V, V2 = V5 = 0V and increasing V1 voltage.

t_{DL} : Over-discharge detection delay time, it is defined as the interval time from V1 voltage falls below V_{DL} until V_{DO} goes to "L", after setting V1 = 3.4V, V2 = V5 = 0V and decreasing V1 voltage.

Discharge Over-Current Detection Delay Time 1 & 2 (Test Circuit 5)

t_{DIOV1} : Discharge over-current detection delay time 1, it is defined as the interval time from V5 voltage exceeds V_{DIOV1} until V_{DO} goes to "L", after setting V1 = 3.4V, V2 = 1.4V, V5 = 0V and increasing V5 voltage.

t_{DIOV2} : Discharge over-current detection delay time 2, it is defined as the interval time from V5 voltage exceeds V_{DIOV2} until V_{DO} goes to "L", after setting V1 = 3.4V, V2 = 1.4V, V5 = 0V and increasing V5 voltage.

Load Short-Circuiting Detection Delay Time (Test Circuit 5)

t_{SHORT} : Load short-circuiting detection delay time, it is defined as the interval time from V5 voltage exceeds V_{SHORT} until V_{DO} goes to "L", after setting V1 = 3.4V, V2 = 1.4V, V5 = 0V and increasing V5 voltage.

Charge Over-Current Detection Delay Time (Test Circuit 5)

t_{CIOV} : Charge over-current detection delay time, it is defined as the interval time from V5 voltage falls below V_{CIOV} until V_{CO} goes to "L", after setting V1 = 3.4V, V2 = 1.4V, V5 = 0V and decreasing V5 voltage.

0V Battery Charge Starting Charger Voltage (0V Battery Charge Enabled Option) (Test Circuit 4)

V_{0CHA} : 0V battery charge starting charger voltage, it is defined as the absolute V2 voltage value at which the current flowing through the CO pin (I_{CO}) exceeds 1.0 μ A when gradually decreasing V2 voltage after setting V1 = V5 = 0V, V2 = V3 = -0.5V.

0V Battery Charge Inhibition Battery Voltage (0V Battery Charge Inhibited Option) (Test Circuit 2)

V_{0INH} : 0V battery charge inhibition battery voltage, it is defined as the V1 voltage at which V_{CO} goes to "L" ($V_{CO} = V_{VM}$) when gradually decreasing V1 voltage after setting V1 = 2.5V, V2 = -2.0V, V5 = 0V.

DETAILED DESCRIPTION

Operation

Normal Status

The SGM41012 monitors the battery voltage between VDD and VSS pins, and the voltage between CS and VSS pins to control charging and discharging.

When the battery voltage is between V_{DL} (over-discharge detection voltage) and V_{CU} (over-charge detection voltage), and the CS pin voltage is between V_{CIOV} (charge over-current detection voltage) and V_{DIOV1} (discharge over-current detection voltage 1), the SGM41012 turns both the charge and discharge control FETs on. This status is defined as normal status.

During normal status, charging and discharging can be freely, the R_{VMD} (resistance between VDD pin and VM pin) and R_{VMS} (resistance between VM pin and VSS pin) are not connected.

Over-Charge Status

$V_{CL} \neq V_{CU}$

In normal status, if the battery voltage rises higher than V_{CU} during charging and it lasts for t_{CU} (over-charge detection delay time) or longer, the SGM41012 will turn the charge control FET off to stop charging. This status is defined as over-charge status, and this status can be released in the following two cases:

1. When $V_{VM} < 0.35V$ (TYP), the SGM41012 releases the over-charge status when the battery voltage falls below V_{CL} (over-charge release voltage).
2. When $V_{VM} \geq 0.35V$ (TYP), the SGM41012 releases the over-charge status when the battery voltage falls below V_{CU} (over-charge detection voltage).

During over-charge status, the VM pin voltage rises due to the charge control FET's parasitic diode once a load is connected to start discharge. If $V_{VM} \geq 0.35V$ (TYP), the SGM41012 releases the over-charge status when the battery voltage $\leq V_{CU}$.

Over-Discharge Status

When the battery voltage falls below V_{DL} during discharging in the normal status and the condition continues for the over-discharge detection delay time (t_{DL}) or longer, the SGM41012 turns the discharge control FET off to stop discharging and goes to the over-discharge status. This status is defined as over-discharge status.

Under the over-discharge status, VDD pin and VM pin are shorted by R_{VMD} in the SGM41012. The VM pin voltage is pulled up by R_{VMD} .

The SGM41012 releases the over-discharge status when the battery voltage reaches V_{DU} or higher even if the battery is not connected to a charger.

When connecting a charger in the over-discharge status, the battery voltage reaches V_{DL} or higher and the SGM41012 releases the over-discharge status if the VM pin voltage is below 0V (TYP).

R_{VMS} is disconnected during the over-discharge status.

Discharge Over-Current Status (Discharge Over-Current 1, Discharge Over-Current 2, Load Short-Circuiting, Load Short-Circuiting 2)

Discharge Over-Current 1, Discharge Over-Current 2, Load Short-Circuiting

When the battery is in a normal status, the CS pin voltage is $\geq V_{DIOV}$ because the discharge current is equal to or higher than the specified value, and the continuous discharge over-current detection delay time (t_{DIOV}) or longer in this status, the discharge control FET is turned off and the discharging is stopped. This status is defined as the discharge over-current status.

Under the discharge over-current status, VM pin and VSS pin are shorted by R_{VMS} in the SGM41012. However, as long as the load is connected, the VM pin voltage is the VDD pin voltage. When the load is disconnected, the VM pin voltage is equal to the VSS pin voltage.

When the VM pin voltage returns to V_{RIOV} or lower, the SGM41012 releases the discharge over-current status.

R_{VMD} is disconnected during the discharge over-current status.

Load Short-Circuiting 2

When the battery is in a normal status, a load causing discharge over-current is connected, and the VM pin voltage is equal to or higher than the load short-circuiting detection voltage 2 (V_{SHORT2}), and the continuous load short-circuiting detection delay time (t_{SHORT}) or longer in this status, the discharge control FET is turned off and discharging is stopped. This status is defined as the load short-circuiting status 2.

Under the load short-circuiting status 2, VM pin and VSS pin are shorted by R_{VMS} in the SGM41012. However, as long as the load is connected, the VM pin voltage is the VDD pin voltage. When the load is disconnected, the VM pin voltage is equal to the VSS pin voltage.

When the VM pin voltage returns to V_{RIOV} or lower, the SGM41012 releases the load short-circuiting status 2.

R_{VMD} is disconnected during the load short-circuiting status 2.

DETAILED DESCRIPTION (continued)

Charge Over-Current Status

When the battery is in a normal status, the CS pin voltage is $\leq V_{C1OV}$ because the charge current is equal to or higher than the specified value, and the continuous charge over-current detection delay time (t_{C1OV}) or longer in this status, the charge control FET is turned off and charging is stopped. This status is defined as the charge over-current status.

The SGM41012 releases the charge over-current status when the discharge current flows and the VM pin voltage is 0.35V (TYP) or higher by removing the charger.

There is no charge over-current protection function during the over-discharge status.

0V Battery Charge Enabled

The 0V charging function allows the charger to charge a battery with a voltage of 0V due to self-discharge. Connect a charger between PCK+ and PCK- pins, the charger voltage reaches 0V battery charge starting charger voltage (V_{0CHG}) or higher, the gate of the charge control FET is connected to the VDD pin voltage.

The external charger makes the voltage between the gate and source of the charge control FET is equal to or higher than the threshold voltage, the charge control FET begins

charging at the same time, the discharge control FET is turned off, and the charging current flows through the parasitic diode of the discharge control FET. If the battery voltage is equal to or higher than V_{DL} , the SGM41012 goes back to the normal status.

Caution: 1. Some battery suppliers do not recommend charging a fully self-discharged Li-Ion rechargeable battery. Please check with your battery supplier to determine whether 0V battery charging is enabled or inhibited.

2. The 0V battery charge priority is higher than the charge over-current detection function. Therefore, a product that enables the use of the 0V battery charge is forced to charge a battery, and when the battery voltage is lower than V_{DL} , the charge over-current cannot be detected.

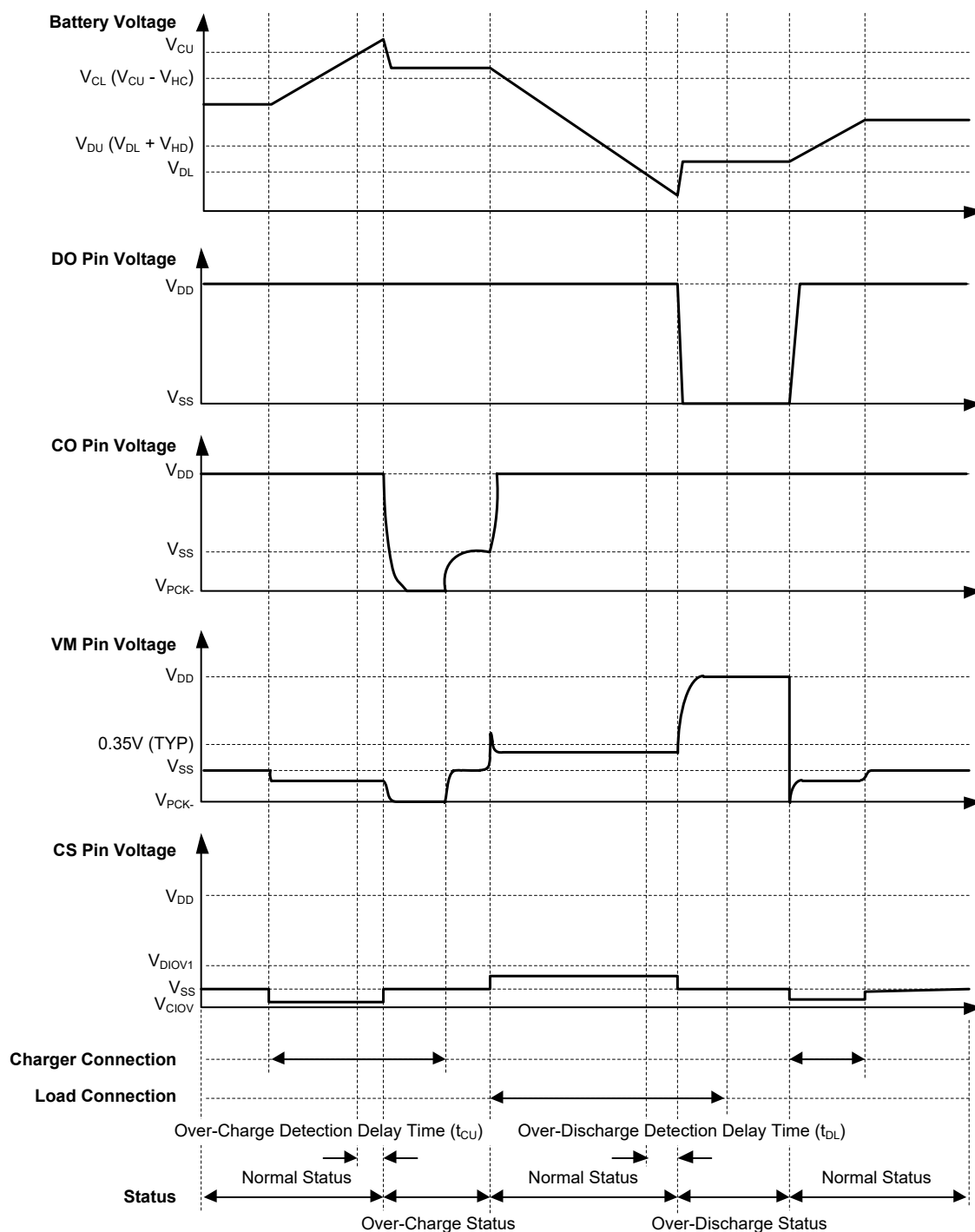
0V Battery Charge Inhibited

This function inhibits charging when connected to an internal short-circuited battery (0V battery). The battery voltage is equal to or lower than the 0V battery charge inhibition battery voltage (V_{0INH}), the gate of the charge control FET is connected to the PCK- pin voltage to inhibit charging. Charging starts when the battery voltage reaches V_{0INH} or higher.

DETAILED DESCRIPTION (continued)

Timing Charts

Over-Charge Detection, Over-Discharge Detection

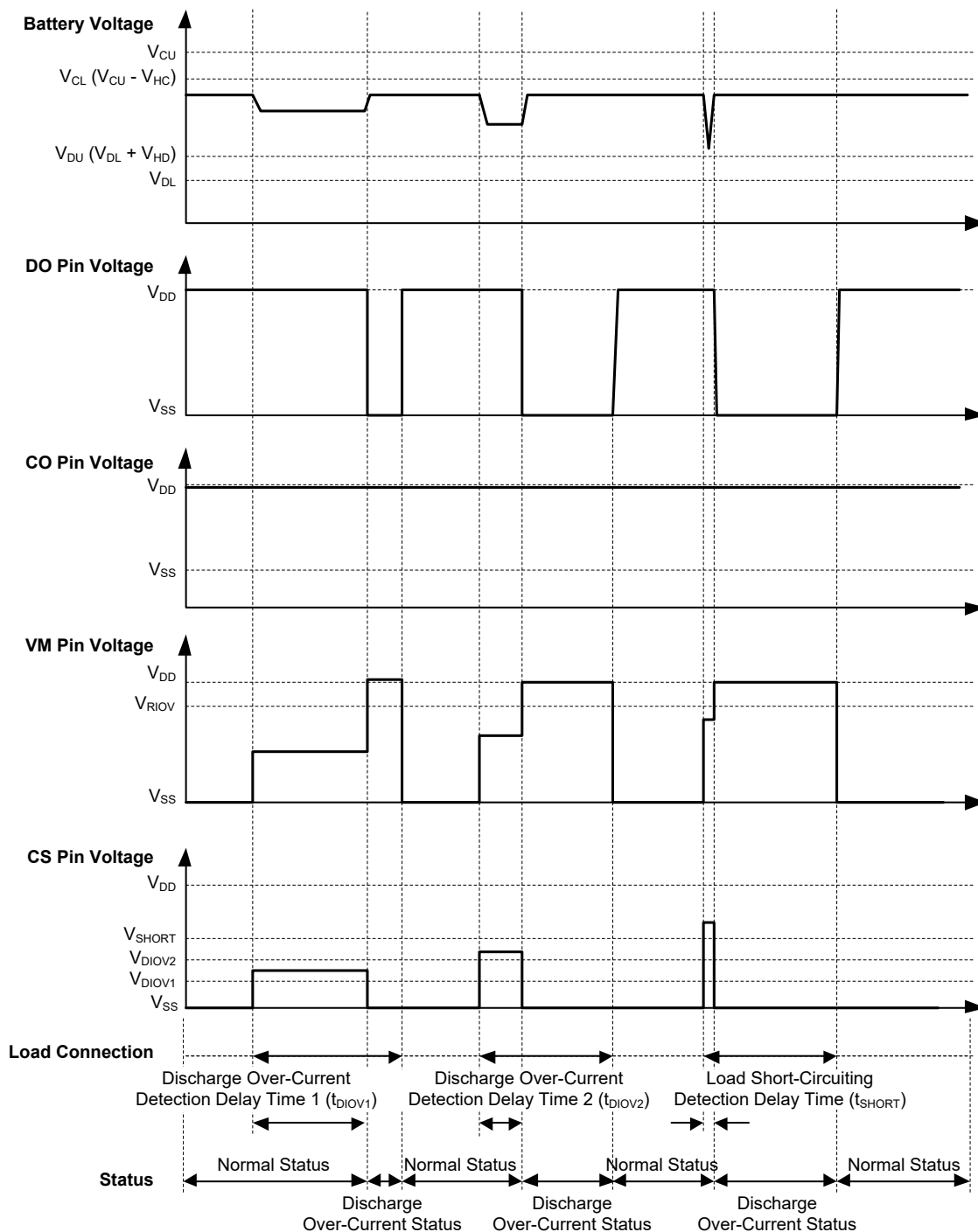


NOTE: Assume that the charger charges at constant current.

Figure 8. Over-Charge Detection, Over-Discharge Detection

DETAILED DESCRIPTION (continued)

Discharge Over-Current Detection

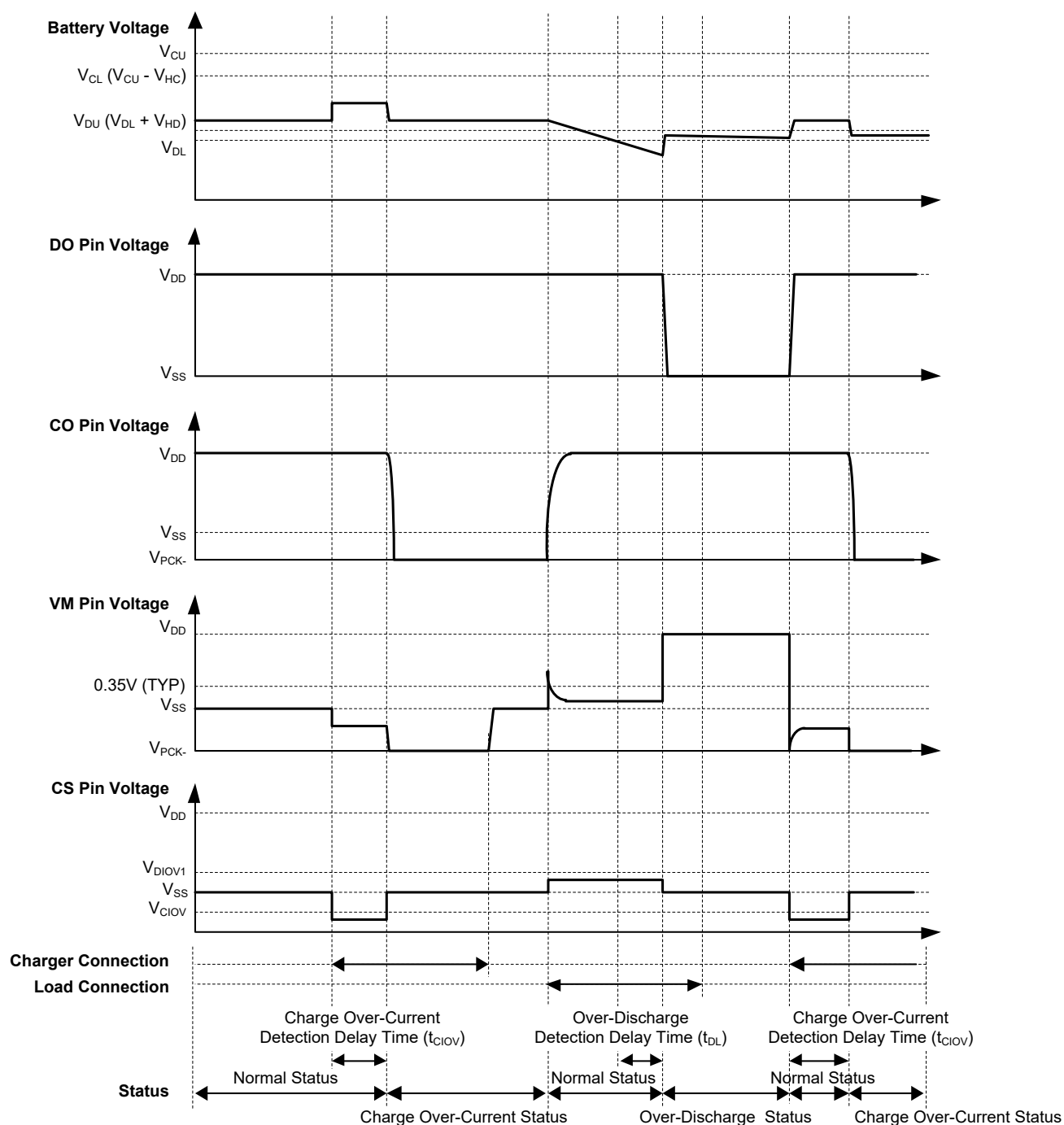


NOTE: Assume that the charger charges at constant current.

Figure 9. Discharge Over-Current Detection

DETAILED DESCRIPTION (continued)

Charge Over-Current Detection



NOTE: Assume that the charger charges at constant current.

Figure 10. Charge Over-Current Detection

DETAILED DESCRIPTION (continued)

Battery Protection IC Connection Example

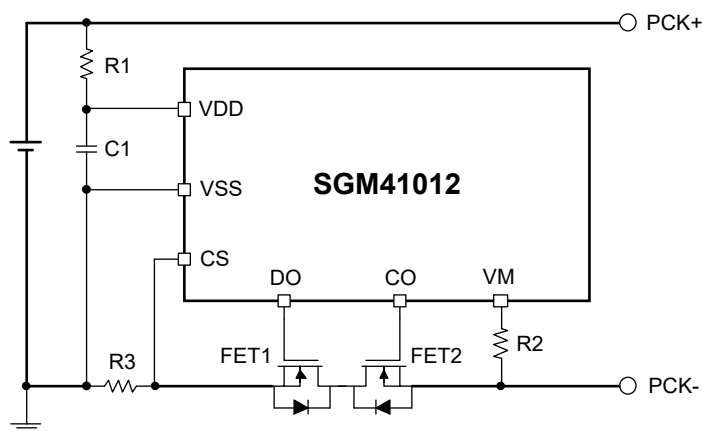


Figure 11. Battery Protection IC Connection Example

Table 4. External Components Constants ^{(3) (4)}

PARAMETER	SYMBOL	FUNCTION	MIN	TYP	MAX
Resistor	R1	ESD Protection, for Power Fluctuation	270Ω	330Ω	1.2kΩ ⁽¹⁾
	R2	ESD Protection, Protection for Reverse Connection of a Charger	270Ω	470Ω	1.5kΩ
	R3	Over-Current Detection		0.75mΩ	
Capacitor	C1	For Power Fluctuation	0.068μF	0.1μF	2.2μF
N-Channel MOSFET	FET1	Discharge Control Threshold Voltage ≤ Over-Discharge Detection Voltage ⁽²⁾			
	FET2	Charge Control Threshold Voltage ≤ Over-Discharge Detection Voltage ⁽²⁾			

NOTES:

1. The over-charge detection voltage accuracy is guaranteed by R1 = 330Ω. Setting the resistance to the other values will reduce the accuracy.
2. When using a FET with a threshold voltage equal to or higher than the over-discharge detection voltage, the discharging can be stopped before the over-discharge is detected.
3. The parameters are subject to change without notice.
4. The circuits other than the connection example have not been confirmed to operate properly, and the connection examples and constants are not guaranteed to function properly. The parameters are set based on a comprehensive evaluation of the actual application.

Precautions

- The application conditions (including the input voltage, output voltage, and load current) cannot exceed the power dissipation.
- Avoid applying an electrostatic discharge to the IC that goes beyond the rated performance of the integrated electrostatic protection circuit.
- Disclaim any dispute arising out of or in connection with the infringement of third party patents by products including this IC.

REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

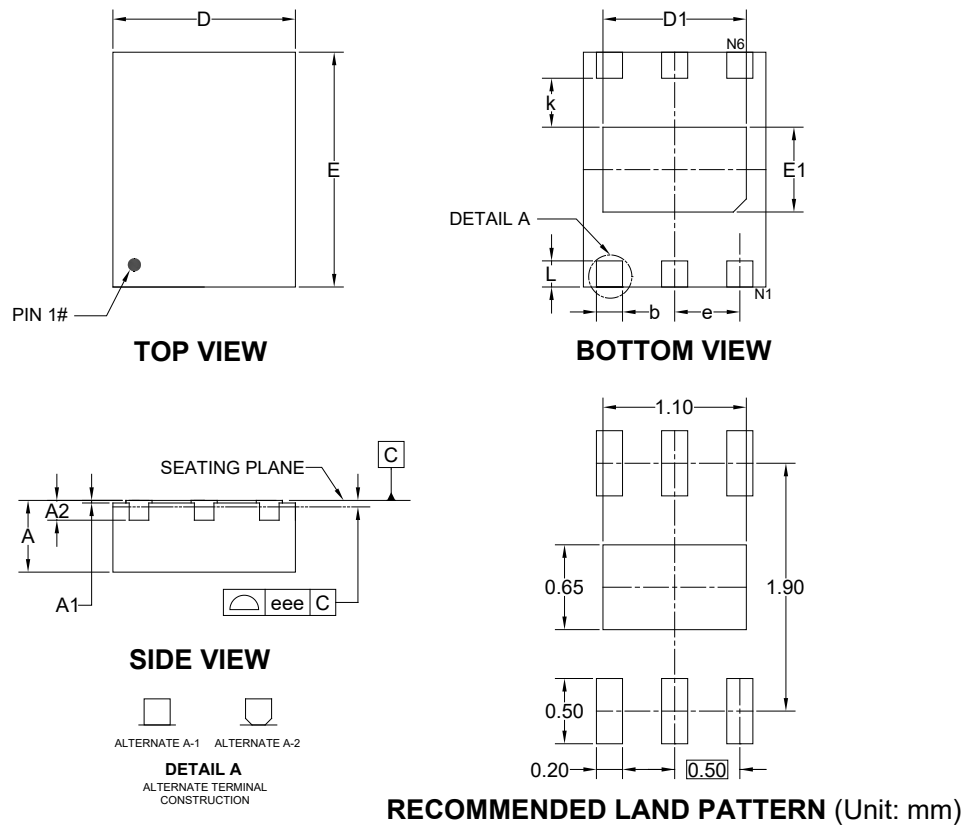
Changes from Original to REV.A (NOVEMBER 2025)

Page

Changed from product preview to production data.....All

PACKAGE OUTLINE DIMENSIONS

UTDFN-1.4×1.8-6L



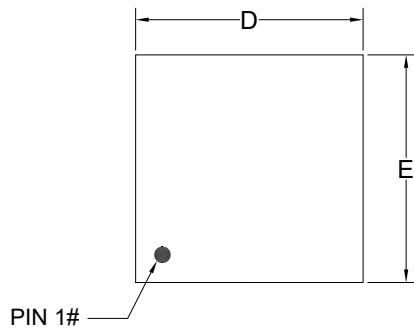
Symbol	Dimensions In Millimeters		
	MIN	NOM	MAX
A	0.500	0.550	0.600
A1	0.000	-	0.050
A2	0.152 REF		
b	0.150	0.200	0.250
D	1.300	1.400	1.500
D1	1.000	1.100	1.200
E	1.700	1.800	1.900
E1	0.550	0.650	0.750
e	0.500 BSC		
k	0.375 REF		
L	0.150	0.200	0.250
eee	-	0.050	-

NOTE: This drawing is subject to change without notice.

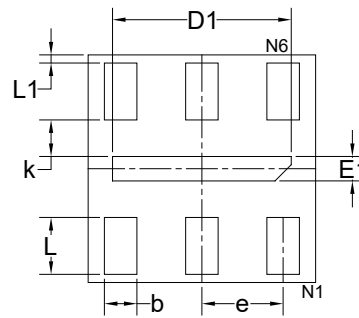
PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

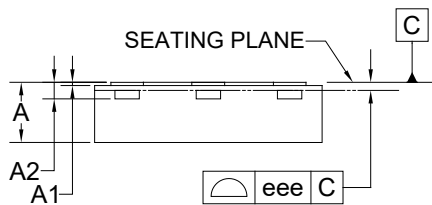
XTDFN-1.4×1.4-6L



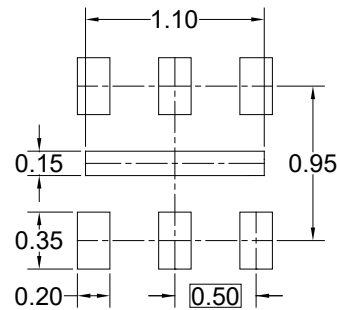
TOP VIEW



BOTTOM VIEW



SIDE VIEW



RECOMMENDED LAND PATTERN (Unit: mm)

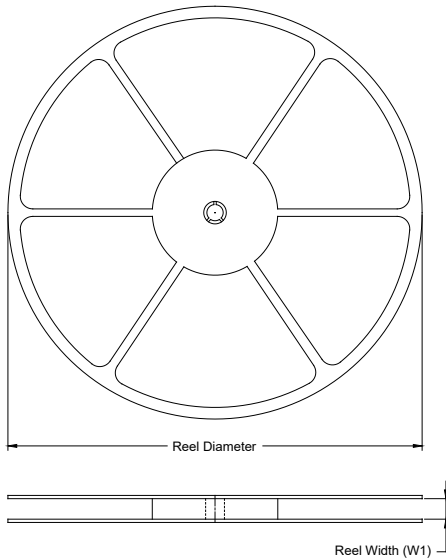
Symbol	Dimensions In Millimeters		
	MIN	NOM	MAX
A	0.320	0.370	0.400
A1	0.000	-	0.050
A2	0.102 REF		
b	0.150	0.200	0.250
D	1.300	1.400	1.500
D1	1.050	1.100	1.150
E	1.300	1.400	1.500
E1	0.100	0.150	0.200
e	0.500 BSC		
k	0.225 REF		
L	0.300	0.350	0.400
L1	0.050 REF		
eee	-	0.050	-

NOTE: This drawing is subject to change without notice.

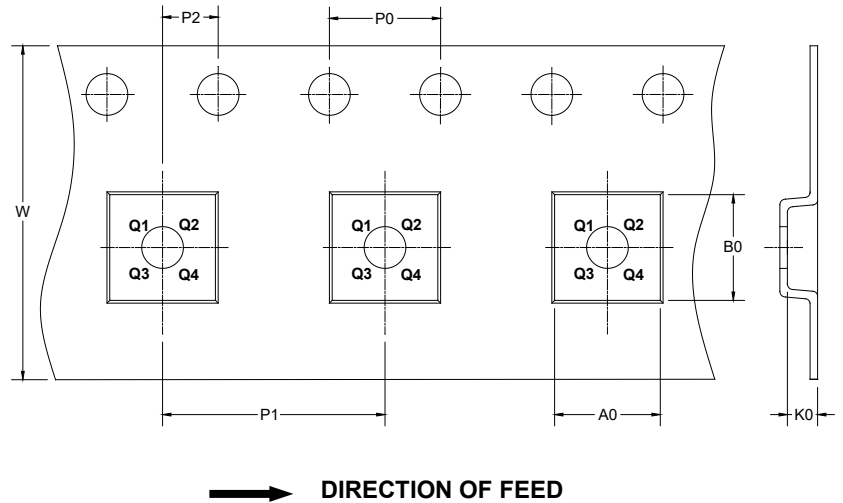
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

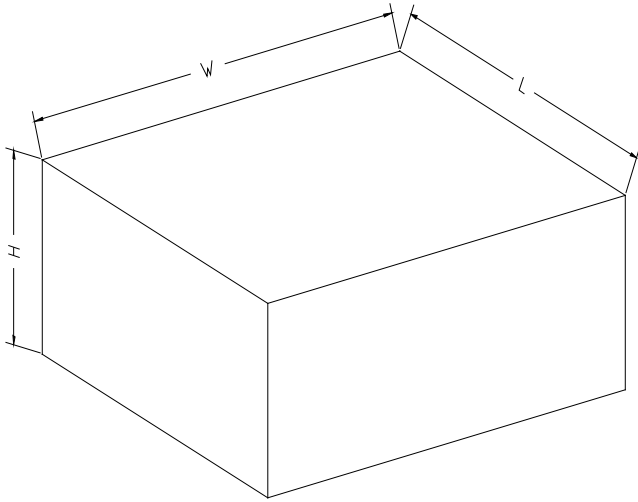
KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
UTDFN-1.4×1.8-6L	7"	9.5	1.60	2.00	0.85	4.0	4.0	2.0	8.0	Q2
XTDFN-1.4×1.4-6L	7"	9.5	1.56	1.56	0.50	4.0	4.0	2.0	8.0	Q2

DD0001

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18

DD0002